TOSHIBA Transistor Silicon NPN Epitaxial Type

## 2SC3474

# Switching Applications Solenoid Drive Applications

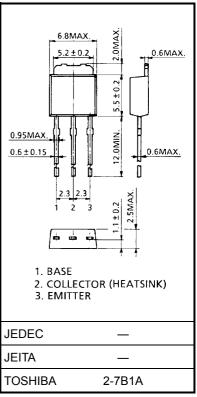
- High DC current gain:  $h_{FE} = 500$  (min) ( $I_{C} = 400$  mA)
- Low saturation voltage:  $V_{CE (sat)} = 0.5 \text{ V (max) (IC} = 300 \text{ mA)}$

#### **Maximum Ratings (Ta = 25°C)**

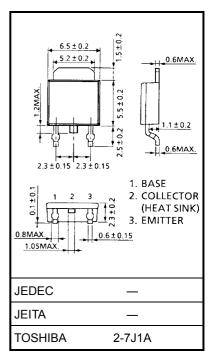
Characteristics		Symbol	Rating	Unit	
Collector-base voltage		$V_{CBO}$	80	V	
Collector-emitter voltage		V <sub>CEO</sub>	80	V	
Emitter-base voltage		V <sub>EBO</sub>	7	V	
Collector current		IC	2	Α	
Base current		Ι <sub>Β</sub>	0.5	Α	
Collector power dissipation	Ta = 25°C	Pc	1.0	W	
	Tc = 25°C	FC	20		
Junction temperature		Tj	150	°C	
Storage temperature range		T <sub>stg</sub>	−55 to 150	°C	

#### **Industrial Applications**

Unit: mm



Weight: 0.36 g (typ.)

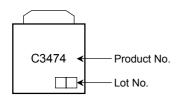


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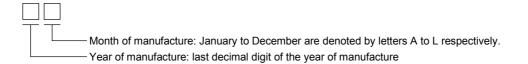
## Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current		I <sub>CBO</sub>	V <sub>CB</sub> = 80 V, I <sub>E</sub> = 0	_	_	1	μΑ
Emitter cut-off current I <sub>EBO</sub>		V <sub>EB</sub> = 7 V, I <sub>C</sub> = 0	_	_	1	μΑ	
Collector-emitter breakdown voltage V (BR) CEO I <sub>C</sub> = 10 mA, I <sub>B</sub> = 0		I <sub>C</sub> = 10 mA, I <sub>B</sub> = 0	80	_	_	V	
DC current gain		h <sub>FE</sub>	V <sub>CE</sub> = 1 V, I <sub>C</sub> = 400 mA	500	_	_	
Collector-emitter s	ector-emitter saturation voltage V <sub>CE (sat)</sub> I <sub>C</sub> = 300 mA, I <sub>B</sub> = 1 mA		_	0.3	0.5	V	
Base-emitter satur	se-emitter saturation voltage V <sub>BE (sat)</sub> I <sub>C</sub> = 300 mA, I <sub>B</sub> = 1 mA		_	_	1.1	V	
Transition frequency		f <sub>T</sub>	V <sub>CE</sub> = 2 V, I <sub>C</sub> = 100 mA	_	85	_	MHz
Collector output capacitance		C <sub>ob</sub>	V <sub>CB</sub> = 10 V, I <sub>E</sub> = 0, f = 1 MHz	_	50	_	pF
Switching time S	Turn-on time	t <sub>on</sub>	20 µs IB1 OUTPUT INPUT O W B2  VCC = 30 V	_	2	_	
	Storage time	t <sub>stg</sub>		_	5	ı	μs
	Fall time	t <sub>f</sub>	I <sub>B1</sub> = -I <sub>B2</sub> = 1 mA, DUTY CYCLE ≤ 1%	_	2		

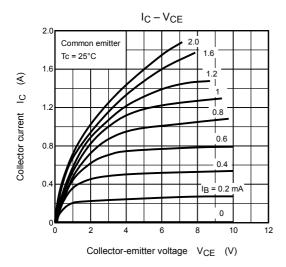
### Marking

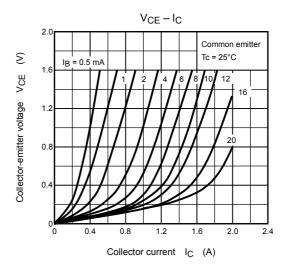


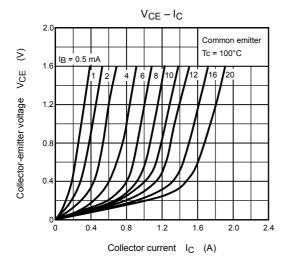
## **Explanation of Lot No.**

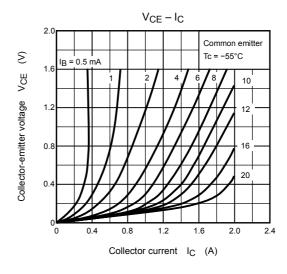


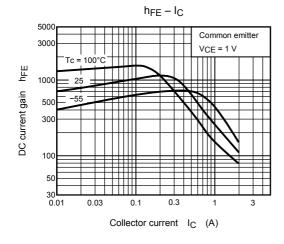
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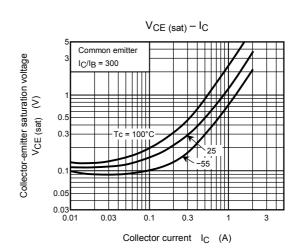




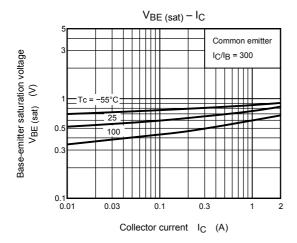


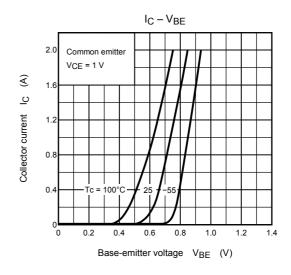


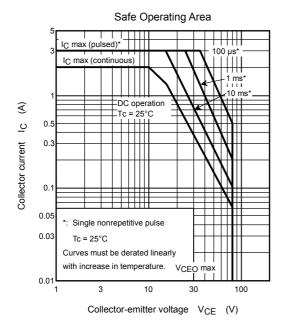


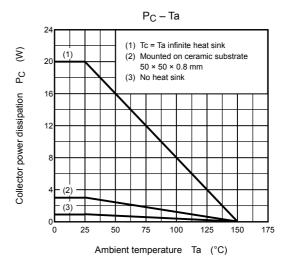


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